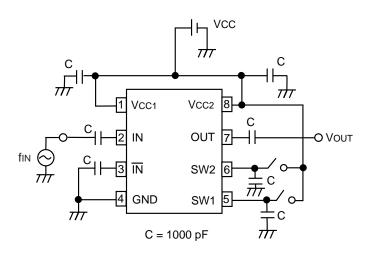
1.0 GHz DIVIDE BY 2/4/8 PRESCALER

FEATURES

NE

- HIGH FREQUENCY OPERATION TO 1 GHz
- SELECTABLE DIVIDE RATIO: ÷2, ÷4, ÷8
- WIDE SUPPLY VOLTAGE RANGE: 2.2 TO 5 V
- LOW SUPPLY CURRENT: 5.3 mA
- SMALL PACKAGE: 8 pin SSOP
- AVAILABLE IN TAPE AND REEL

TEST CIRCUIT



UPB1509GV

DESCRIPTION

The UPB1509GV is a Silicon MMIC digital prescaler manufactured with the NESAT™ IV silicon bipolar process. It features frequency response to 1 GHz, selectable divide-by-two, four, or eight modes, and operates from a 3 to 5 volt supply while drawing only 5.3 milliamps. The device is housed in a small 8 pin SSOP package that contributes to system miniaturization. The low power consumption and wide supply range makes the device well suited for cellular and cordless telephones as well as DBS receiver applications.

ELECTRICAL CHARACTERISTICS (TA = -40 to +85°C, Vcc = 2.2 to 5.5 V, unless otherwise noted)

	PART NUMBER PACKAGE OUTLINE		UPB1509GV S08		
SYMBOLS	SYMBOLS PARAMETERS AND CONDITIONS		MIN	ТҮР	MAX
lcc	Supply Current, No Input Signal, Vcc = 3 V	mA	2.5	5.0	5.9
fin (u)	Upper Limit Operating Frequency, PIN = -20 to 0 dBm PIN = -20 to -5 dBm @ ÷ 2 @ ÷ 4 @ ÷ 8	MHz MHz MHz MHz	500 700 800 1000		
fin (L)	Lower Limit Operating Frequency, $P_{IN} = -20$ to 0 dBm $P_{IN} = -20$ to -5 dBm	MHz MHz			50 500
Pin	Input Power, fin = 50 to 1000 MHz fin = 50 to 500 MHz	dBm dBm	-20 -20		-5 0
Vout	Output Voltage, R∟ = 200 Ω	VP-P	0.1	0.2	
VIN(H)	Division Ratio Control Voltage High	V		Vcc	
VIN(L)	Division Ratio Control Voltage Low	V		OPEN	

California Eastern Laboratories

ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

SYMBOLS PARAMETERS		UNITS	RATINGS
VCC1, VCC2	Supply Voltage	V	6.0
Vin	Input Voltage	V	6.0
PD	Power Dissipation ²	mW	250
Тор	Operating Temperature	°C	-45 to +85
Tstg	Storage Temperature	°C	-55 to +150

Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.

 Mounted on a double-sided copper clad 50x50x1.6 mm epoxy glass PWB (T_A = +85°C).

PRODUCT LINE-UP

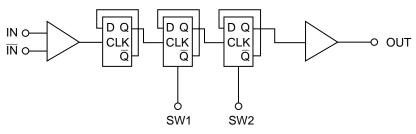
RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	UNITS	MIN	ТҮР	MAX
VCC1, VCC2	Supply Voltage	V	2.2	3.0	5.5
Тор	Operating Temperature	°C	-40	+25	+85

Product No.	lcc (mA)	Vcc (V)	÷2 fin (MHz)	÷4 fin (MHz)	÷8 fin (MHz)	Package
UPB587G	5.5	2.2 to 3.5	50 to 300	50 to 600	50 to 1000	8 pin SOP
UPB1509GV	5.3	2.2 to 5.5	50 to 1000	50 to 1000	50 to 1000	8 pin SSOP

Note: This table shows Typ. values only.

INTERNAL BLOCK DIAGRAM

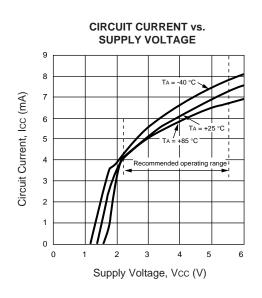


PIN DESCRIPTIONS

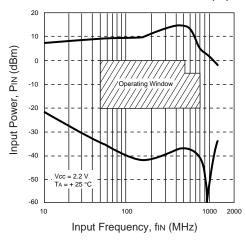
Pin no.	Symbol	Applied Voltage	Pin Voltage	Description				
1	VCC1	2.2 to 5.5	_	Power supply pin of input amplifier and dividers. This pin must be equipped with bypass capacitor (eg 1000 pF) to ground.				
2	IN	-	1.7 to 4.95	.95 Signal input pin. This pin should be coupled with a capacitor (eg 1000 pF				
3	ĪN	-	1.7 to 4.95	Signal input bypass pin. This pin must be equipped with a bypass capacitor (eg 1000 pF) to ground.				
4	GND	0	_	Ground pin. Ground pattern on the board should be formed as wide as possible to minimize ground impedance.				
5	SW1	H/L (VCC/OPEN)	_	Divided ratio control pin. Divide ratio can be controlled by the following input voltages to these pins.				
0	SW2	H/L				5	SW2	
6	5002					H (Vcc)	L (OPEN)	
		(VCC/OPEN)		SW1	H (Vcc)	1/2	1/4	
				0001	L (OPEN)	1/4	1/8	
				These pins must	each be eq	uipped with a	bypass capac	itor to ground.
7	OUT	-	1.0 to 4.7	Divided frequency output pin. This pin is designed as an emitter follower output. This pin can output 0.1 Vp-p min with a 200 Ω load. This pin should be coupled to load device with a capacitor (eg 1000 pF).				
8	VCC2	2.2 to 5.5	_	Power supply pin of output buffer amplifier. This pin must be equipped with bypass capacitor (eg 1000 pF) to ground.				

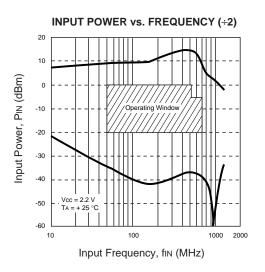
TYPICAL PERFORMANCE CURVES

(TA = +25°C unless otherwise noted)

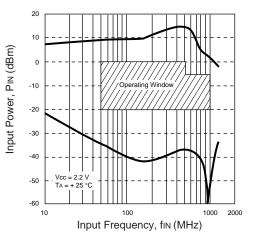


INPUT POWER vs. FREQUENCY (÷4)



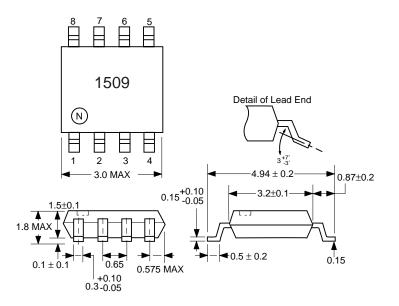


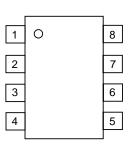
INPUT POWER vs. FREQUENCY (+8)



OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE S08





PIN CONNECTIONS

1. Vcc1	5.	SW1
2. IN	6.	SW2
3. ĪN	7.	OUT
4. GND	8.	VCC2

ORDERING INFORMATION

PART NUMBER	QUANTITY
UPB1509GV-E1	1000/Reel

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